

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	292388	((metal and hydrogen) and oxide)	US-PGPU B; USPAT; USOCR	OR	ON	2005/06/21 14:32
L2	516407	(semiconductor ((amorphous near5 silicon) a-silicon (alpha near3 silicon) alpha-silicon alpha-Si))	US-PGPU B; USPAT; USOCR	OR	ON	2005/06/21 14:33
L3	46624	1 and 2	US-PGPU B; USPAT; USOCR	OR	ON	2005/06/21 10:37
L4	39251	3 and (anneal\$3 heat\$3)	US-PGPU B; USPAT; USOCR	OR	ON	2005/06/21 14:33
L5	5992	4 and peel\$3	US-PGPU B; USPAT; USOCR	OR	ON	2005/06/21 14:33
L6	5271	5 and (bond\$3 attach\$3 adher\$3)	US-PGPU B; USPAT; USOCR	OR	ON	2005/06/21 14:35
L7	4703	6 and (substrate wafer)	US-PGPU B; USPAT; USOCR	OR	ON	2005/06/21 14:35
L8	1244	7 and (TFT (thin near5 film near5 transistor))	US-PGPU B; USPAT; USOCR	OR	ON	2005/06/21 14:53
L9	1235	8 and (((tungsten "W") (titanium "Ti") (tantalum "Ta") (molybdenum "Mo") (chromium "Cr") (iron "Fe") (nickel "Ni") (cobalt "Co") (zirconium "Zr") (zinc "Zn") (ruthenium "Ru") (rhodium "Rh") (palladium "Pd") (osmium "Os") (iridium "Ir") (platinum "Pt"))	US-PGPU B; USPAT; USOCR	OR	ON	2005/06/21 14:36
L10	14895	((metal and hydrogen) and oxide)	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/21 14:32
L11	1059958	(semiconductor ((amorphous near5 silicon) a-silicon (alpha near3 silicon) alpha-silicon alpha-Si))	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/21 14:33
L12	1516	10 and 11	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/21 14:33

L13	537	12 and (anneal\$3 heat\$3)	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/21 14:33
L14	37244	4 and (peel\$3 detach\$3 remov\$3 separat\$3)	US-PGPU B; USPAT; USOCR	OR	ON	2005/06/21 14:34
L15	27802	14 and (bond\$3 attach\$3 adher\$3)	US-PGPU B; USPAT; USOCR	OR	ON	2005/06/21 14:35
L16	24293	15 and (substrate wafer)	US-PGPU B; USPAT; USOCR	OR	ON	2005/06/21 14:35
L17	4129	16 and (TFT (thin near5 film near5 transistor))	US-PGPU B; USPAT; USOCR	OR	ON	2005/06/21 14:36
L18	4071	17 and ((tungsten "W") (titanium "Ti") (tantalum "Ta") (molybdenum "Mo") (chromium "Cr") (iron "Fe") (nickel "Ni") (cobalt "Co") (zirconium "Zr") (zinc "Zn") (ruthenium "Ru") (rhodium "Rh") (palladium "Pd") (osmium "Os") (iridium "Ir") (platinum "Pt"))	US-PGPU B; USPAT; USOCR	OR	ON	2005/06/21 14:37
L19	2836	18 not 9	US-PGPU B; USPAT; USOCR	OR	ON	2005/06/21 14:38
L20	18	13 and (TFT (thin near5 film near5 transistor))	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/21 14:53